

NCE6008AS

NCE N-Channel Enhancement Mode Power MOSFET

Description

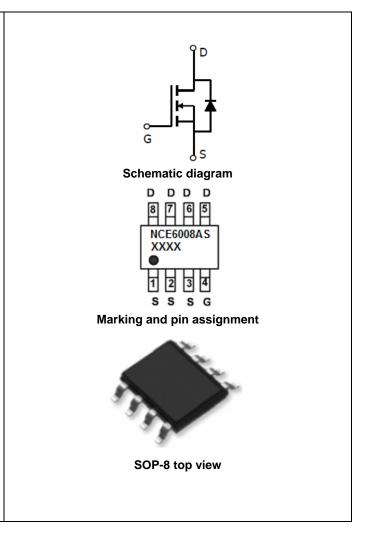
The NCE6008AS uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

- $V_{DS} = 60V, I_D = 8A$ $R_{DS(ON)} < 20m\Omega @ V_{GS} = 10V$ (Typ:14.5m Ω)
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Low gate to drain charge to reduce switching losses

Application

- Power switching application
- Load switch



Package Marking and Ordering Information

| | J | <u> </u> | | | |
|----------------|-----------|----------------|-----------|------------|----------|
| Device Marking | Device | Device Package | Reel Size | Tape width | Quantity |
| NCE6008AS | NCE6008AS | SOP-8 | - | - | - |

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

| 3 (§ | , | | |
|--|-----------------------|------------|------|
| Parameter | Symbol | Limit | Unit |
| Drain-Source Voltage | V _{DS} | 60 | V |
| Gate-Source Voltage | V _{GS} | ±20 | V |
| Drain Current-Continuous | I _D | 8 | А |
| Drain Current-Continuous(T _C =100 °C) | I _D (100℃) | 5.6 | А |
| Pulsed Drain Current | I _{DM} | 32 | А |
| Maximum Power Dissipation | P _D | 2.1 | W |
| Operating Junction and Storage Temperature Range | T_{J}, T_{STG} | -55 To 150 | °C |

Thermal Characteristic

| Thermal Resistance, Junction-to-Ambient (Note 2) | $R_{\theta JA}$ | 60 | °C/W | |
|--|-----------------|----|------|--|
|--|-----------------|----|------|--|



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Electrical Characteristics (TC=25°C unless otherwise noted)

| Parameter | Symbol | Condition | Min | Тур | Max | Unit |
|------------------------------------|---------------------|--|-----|------|------|------|
| Off Characteristics | | | • | • | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V I _D =250μA | 60 | | - | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =60V,V _{GS} =0V | - | - | 1 | μA |
| Gate-Body Leakage Current | I _{GSS} | V_{GS} =±20 V , V_{DS} =0 V | - | - | ±100 | nA |
| On Characteristics (Note 3) | | | • | • | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}$, $I_{D}=250\mu A$ | 1.4 | 1.9 | 2.5 | V |
| Drain-Source On-State Resistance | R _{DS(ON)} | V _{GS} =10V, I _D =8A | - | 14.5 | 20 | mΩ |
| Forward Transconductance | g FS | V _{DS} =5V,I _D =8A | 18 | - | - | S |
| Dynamic Characteristics (Note4) | | | • | • | | |
| Input Capacitance | C _{lss} | \/ 00\/\\ 0\/ | - | 2050 | - | PF |
| Output Capacitance | C _{oss} | V_{DS} =30V, V_{GS} =0V, F=1.0MHz | - | 158 | - | PF |
| Reverse Transfer Capacitance | C _{rss} | r=1.0lvlm2 | - | 120 | - | PF |
| Switching Characteristics (Note 4) | | | | • | | |
| Turn-on Delay Time | t _{d(on)} | | - | 7 | - | nS |
| Turn-on Rise Time | t _r | V_{DD} =30V, R_L =1 Ω | - | 5.5 | - | nS |
| Turn-Off Delay Time | t _{d(off)} | V_{GS} =10V, R_{GEN} =3 Ω | - | 29 | - | nS |
| Turn-Off Fall Time | t _f | | - | 4.5 | - | nS |
| Total Gate Charge | Qg | V -20VI -0A | - | 50 | - | nC |
| Gate-Source Charge | Q _{gs} | V_{DS} =30V, I_{D} =8A, V_{GS} =10V | - | 6 | - | nC |
| Gate-Drain Charge | Q _{gd} | V _{GS} =10V | - | 15 | - | nC |
| Drain-Source Diode Characteristics | | | | • | | |
| Diode Forward Voltage (Note 3) | V _{SD} | V _{GS} =0V,I _S =8A | - | - | 1.2 | V |
| Diode Forward Current (Note 2) | Is | - | | - | 8 | Α |
| Reverse Recovery Time | t _{rr} | TJ = 25°C, IF =8A | - | 28 | - | nS |
| Reverse Recovery Charge | Qrr | $di/dt = 100A/\mu s^{(Note3)}$ | - | 40 | - | nC |

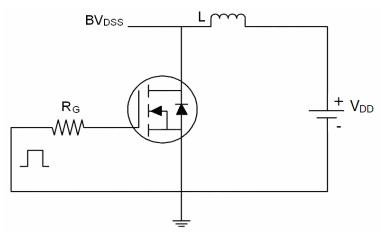
Notes:

- $\textbf{1.} \ \textbf{Repetitive Rating: Pulse width limited by maximum junction temperature.}$
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- **3.** Pulse Test: Pulse Width ≤ 300μ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production

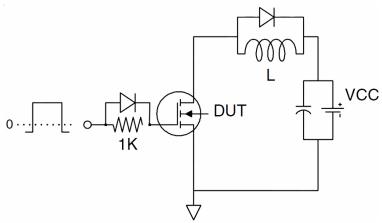
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Test Circuit

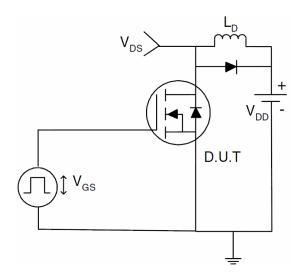
1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit



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Typical Electrical and Thermal Characteristics (Curves)

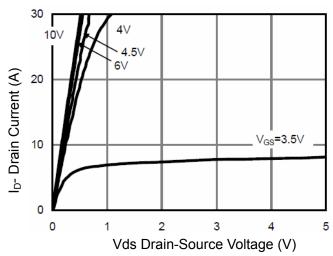


Figure 1 Output Characteristics

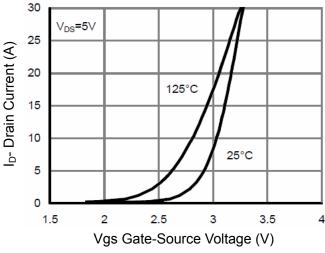


Figure 2 Transfer Characteristics

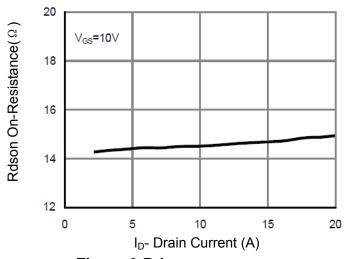


Figure 3 Rdson- Drain Current

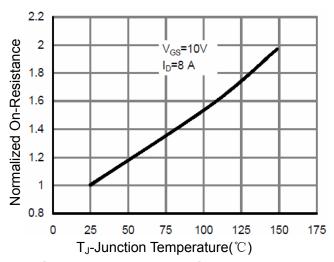


Figure 4 Rdson-JunctionTemperature

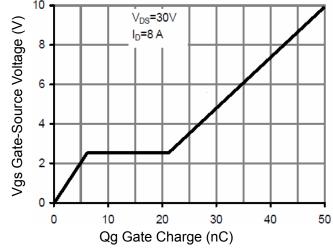


Figure 5 Gate Charge

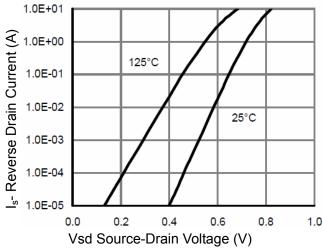
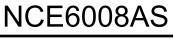
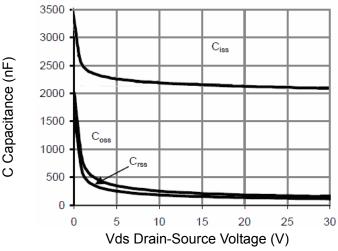


Figure 6 Source- Drain Diode Forward

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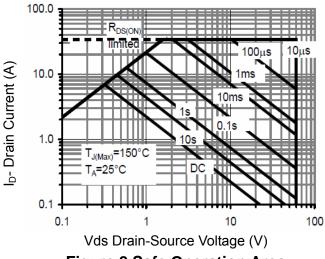




12 10 Ip- Drain Current (A) 8 6 2 0 0 25 50 75 100 125 150 T_J-Junction Temperature(°C)

Figure 7 Capacitance vs Vds

Figure 9 Current De-rating



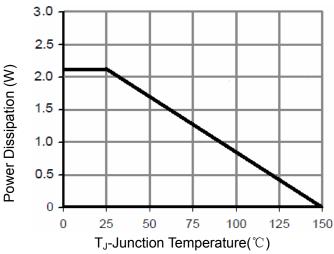
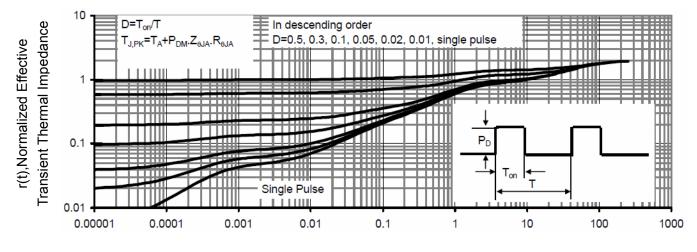


Figure 8 Safe Operation Area

Figure 10 Power De-rating



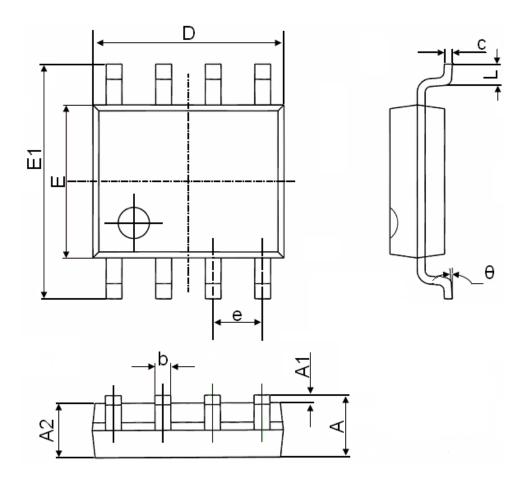
Square Wave Pluse Duration(sec)

Figure 11 Normalized Maximum Transient Thermal Impedance

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SOP-8 Package Information



| Symbol | Dimensions | n Millimeters | Dimensions In Inches | | |
|--------|------------|---------------|----------------------|-------|--|
| | Min. | Max. | Min. | Max. | |
| А | 1.350 | 1.750 | 0.053 | 0.069 | |
| A1 | 0.100 | 0.250 | 0.004 | 0.010 | |
| A2 | 1.350 | 1.550 | 0.053 | 0.061 | |
| b | 0.330 | 0.510 | 0.013 | 0.020 | |
| С | 0.170 | 0.250 | 0.006 | 0.010 | |
| D | 4.700 | 5.100 | 0.185 | 0.200 | |
| E | 3.800 | 4.000 | 0.150 | 0.157 | |
| E1 | 5.800 | 6.200 | 0.228 | 0.244 | |
| е | 1.270 | 1.270(BSC) | | (BSC) | |
| L | 0.400 | 1.270 | 0.016 | 0.050 | |
| θ | 0° | 8° | 0° | 8° | |



http://www.ncepower.com

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